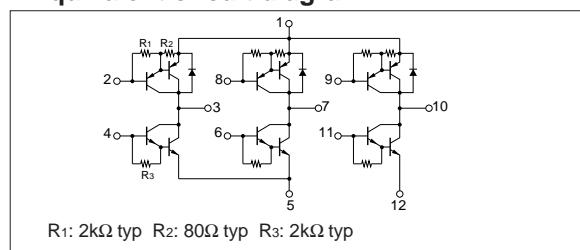
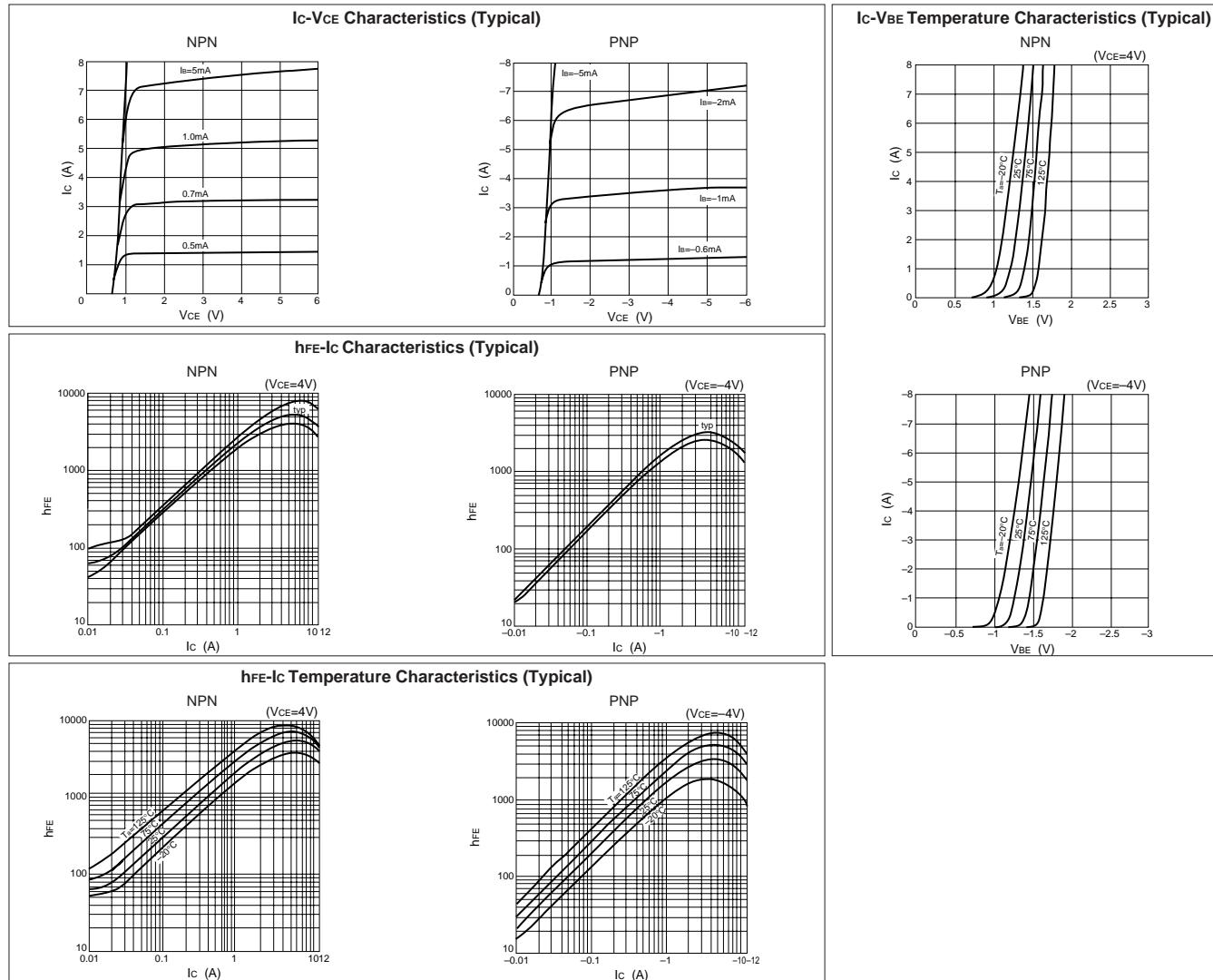


**Absolute maximum ratings**

Symbol	Ratings		(Ta=25°C)
	NPN	PNP	
V <sub>CBO</sub>	60	-60	V
V <sub>CEO</sub>	60	-60	V
V <sub>EBO</sub>	6	-6	V
I <sub>c</sub>	8	-8	A
I <sub>CP</sub>	12 (PW≤1ms, Du≤50%)	-12 (PW≤1ms, Du≤50%)	A
I <sub>FECL</sub>	—	-8	A
I <sub>FECP</sub>	—	-12	A
I <sub>B</sub>	0.5	-0.5	A
P <sub>T</sub>	5 (Ta=25°C) 25 (Tc=25°C)		W
V <sub>iso</sub>	1000 (Between fin and lead pin, AC)		V <sub>rms</sub>
T <sub>j</sub>	150		°C
T <sub>stg</sub>	-40 to +150		°C
θ <sub>j-c</sub>	5		°C/W

**Equivalent circuit diagram**

**Characteristic curves**


## Electrical characteristics

(Ta=25°C)

Symbol	NPN						PNP					
	Specification			Unit	Conditions	Specification			Unit	Conditions		
	min	typ	max			min	typ	max				
I <sub>CO</sub>			10	μA	V <sub>CB</sub> =60V			-10	μA	V <sub>CB</sub> =-60V		
I <sub>EBO</sub>			10	μA	V <sub>EB</sub> =6V			-10	mA	V <sub>EB</sub> =-6V		
V <sub>C EO</sub>	60			V	I <sub>C</sub> =10mA	-60			V	I <sub>C</sub> =-10mA		
h <sub>FE</sub>	2000	5000	12000		V <sub>CE</sub> =4V, I <sub>C</sub> =5A	2000	5000	12000		V <sub>CE</sub> =-4V, I <sub>C</sub> =-5A		
V <sub>CE(sat)</sub>			1.5	V	I <sub>C</sub> =5A, I <sub>B</sub> =10mA			-1.5	V	I <sub>C</sub> =-5A, I <sub>B</sub> =-10mA		
V <sub>BE(sat)</sub>			2.0	V				-2.0	V			
V <sub>FEC</sub>		—		V				2.0	V	I <sub>FEC</sub> =5A		
t <sub>rr</sub>		—		μs				1.0	μs	I <sub>FEC</sub> =±0.5A		
t <sub>on</sub>		0.5		μs	V <sub>CC</sub> =25V, I <sub>C</sub> =5A, I <sub>B1</sub> =-I <sub>B2</sub> =10mA			0.5	μs	V <sub>CC</sub> =-25V, I <sub>C</sub> =-5A, I <sub>B1</sub> =-I <sub>B2</sub> =-10mA		
t <sub>stg</sub>		2.0		μs				1.4	μs			
t <sub>r</sub>		1.2		μs				0.6	μs			
f <sub>T</sub>		50		MHz	V <sub>CE</sub> =12V, I <sub>E</sub> =-1A			100	MHz	V <sub>CE</sub> =-12V, I <sub>E</sub> =1A		
C <sub>ob</sub>		100		pF	V <sub>CB</sub> =10V, f=1MHz			130	pF	V <sub>CB</sub> =-10V, f=1MHz		

## Characteristic curves

